

Features

- 1.2kV Schottky Rectifier
- Zero Reverse Recovery Current
- High-Frequency Operation
- Temperature-Independent Switching
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies (SMPS)
- Boost diodes in PFC or DC/DC stages
- Free Wheeling Diodes in Inverter stages
- AC/DC converters

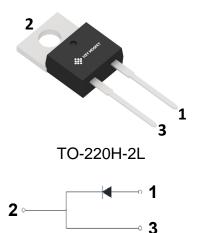




Part Number	Package	Qty(PCS)		
IDH20G120C5XKSA1	TO-220H-2L	50		

Maximum Ratings (T_C=25°C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
V _{RRM}	Repetitive Peak Reverse Voltage	1200	V		
V _{RSM}	Surge Peak Reverse Voltage	1300	V		
V _R	DC Peak Reverse Voltage	1200	V		
I _F	Continuous Forward Current	54.5 26 20	А	T _c =25°C T _c =135°C T _c =150°C	Fig. 3
I _{FRM}	Repetitive Peak Forward Surge Current	91 61	А	T_c =25°C, t_p =10 ms, Half Sine Pulse T_c =110°C, t_p =10 ms, Half Sine Pulse	
I _{FSM}	Non-Repetitive Forward Surge Current	130 110	А	T_c =25°C, t_p =10 ms, Half Sine Pulse T_c =110°C, t_p =10 ms, Half Sine Pulse	Fig. 8
I _{F,Max}	Non-Repetitive Peak Forward Current	1150 950	А	T_c =25°C, t_p =10 ms, Pulse T_c =110°C, t_p =10 ms, Pulse	Fig. 8
P _{tot}	Power Dissipation	250 112.5	W	T _c =25°C T _c =110°C	Fig. 4
dV/dt	Diode dV/dt ruggedness	200	V/ns	V _R =0-960V	
∫i²dt	i²t value	84.5 60.5	A²s	T_c =25°C, t_p =10 ms T_c =110°C, t_p =10 ms	
T _J	Operating Junction Range	-55 to +175	°C		
T_{stg}	Storage Temperature Range	-55 to +135	°C		
	TO-220 Mounting Torque	1 8.8	Nm lbf-in	M3 Screw 6-32 Screw	





Electrical Characteristics

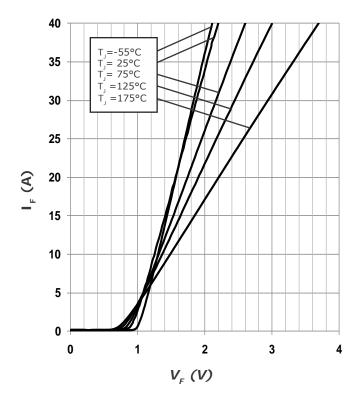
Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V _F	Forward Voltage	1.5 2.2	1.8 3	V	I _F = 20 A T _J =25°C I _F = 20 A T _J =175°C	Fig. 1
I _R	Reverse Current	35 65	200 400	μΑ	V _R = 1200 V T _J =25°C V _R = 1200 V T _J =175°C	Fig. 2
Q _c	Total Capacitive Charge	99		nC	$V_R = 800 \text{ V, } I_F = 20A$ $di/dt = 200 \text{ A/}\mu\text{s}$ $T_J = 25^{\circ}\text{C}$	Fig. 5
С	Total Capacitance	1500 93 67		pF	V _R = 0 V, T _J = 25°C, f = 1 MHz V _R = 400 V, T _J = 25°C, f = 1 MHz V _R = 800 V, T _J = 25°C, f = 1 MHz	Fig. 6
E _c	Capacitance Stored Energy	28		μJ	V _R = 800 V	Fig. 7

Note: This is a majority carrier diode, so there is no reverse recovery charge.

Thermal Characteristics

Symbol Parameter		Тур.	Unit	Note
$R_{\theta JC}$	Thermal Resistance from Junction to Case	0.6	°C/W	Fig. 9

Typical Performance





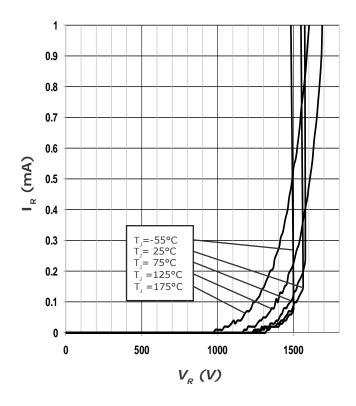


Figure 2. Reverse Characteristics



Typical Performance

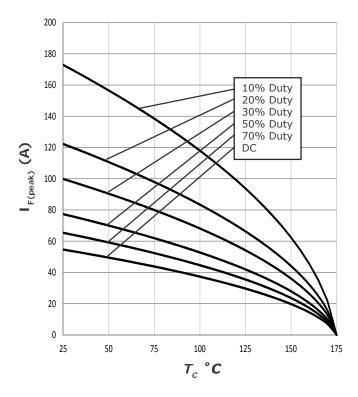


Figure 3. Current Derating

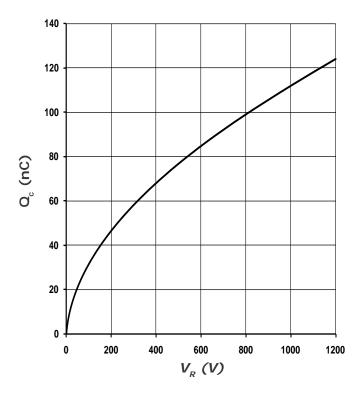


Figure 5. Recovery Charge vs. Reverse Voltage

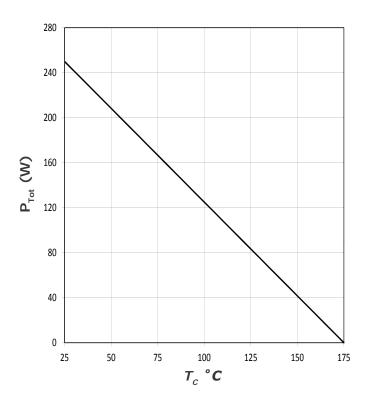


Figure 4. Power Derating

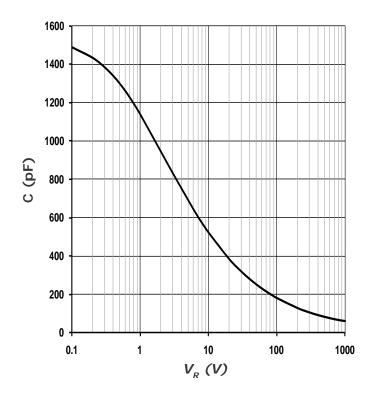
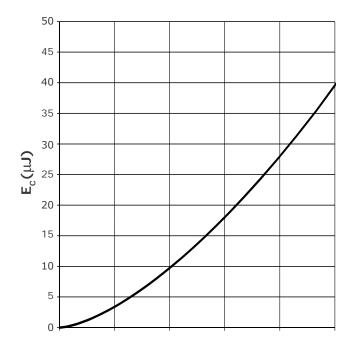


Figure 6. Capacitance vs. Reverse Voltage



Typical Performance



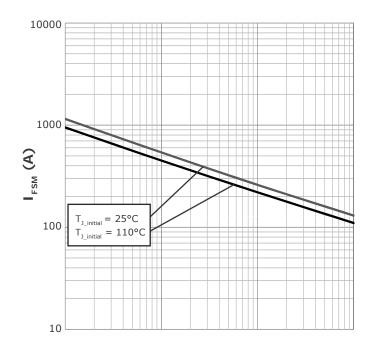


Figure 7. Typical Capacitance Stored Energy

Figure 8. Non-Repetitive Peak Forward Surge Current versus Pulse Duration (sinusoidal waveform)

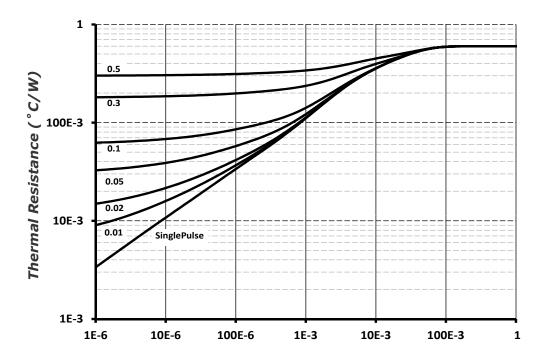


Figure 9. Transient Thermal Impedance *T (Sec)*

Diode Model

$$\begin{array}{c|c} - & & \\ \hline V_T & R_T \end{array}$$

$$V_{fT} = V_T + If * R_T$$

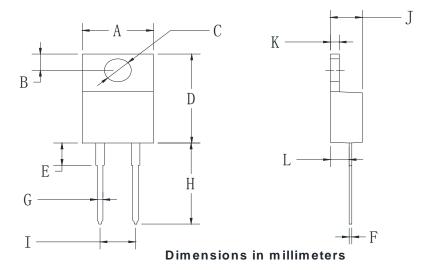
$$V_T = 0.97 + (T_J^* - 1.40^*10^{-3})$$

 $R_T = 0.023 + (T_J^* 2.71^*10^{-4})$

Note: T_j = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C

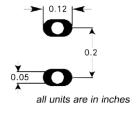


Package Information TO-220H-2L



TO-220H-2L					
Dim	Min	Max			
Α	9.5	10.9			
В	2.22	3.27			
С	3.34	4.31			
D	14.5	15.5			
Е	3.16	4.46			
F	0.28	0.64			
G	0.68	0.94			
Н	13.06	14.62			
I	4.55	5.60			
J	4.04	5.1			
K	1.14	1.4			
L	2.14	3.19			

Recommended Solder Pad Layout



TO-220H2L

IDH20G120C5XKSA1

Silicon Carbide Schottky Diode

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